Thermochemical and Mechanical Stabilities of the Oxide Scale of ZrB$_2$+SiC and Oxygen Transport Mechanisms

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Refractory diboride with silicon carbide additive has a unique oxide scale microstructure with two condensed oxide phases (solid + liquid), and demonstrates oxidation resistance superior to either monolithic diboride or silicon carbide. We rationalize that this is because the silica-rich liquid phase can retreat outward to remove the high SiO$_2$ gas volatility region, while still holding onto the zirconia skeleton mechanically by capillary forces, to form a “solid pillars, liquid roof” scale architecture and maintain barrier function. Basic assessment of the oxygen carriers in the borosilicate liquid in oxygen-rich condition is performed using first-principles calculations. It is estimated from entropy and mobility arguments that above a critical temperature $T_c \sim 1500$ °C, the dominant oxygen carriers should be network defects, such as peroxyl linkage or oxygen-deficient centers, instead of molecular O$_2$ as in the Deal–Grove model. These network defects will lead to sublinear dependence of the oxidation rate with external oxygen partial pressure. The present work suggests that there could be significant room in improving the high-temperature oxidation resistance by refining the oxide scale microstructure as well as controlling the glass chemistry.

1. Introduction

Refractory diborides (HfB$_2$, ZrB$_2$) with 20–30 vol% SiC additive are prominent ultrahigh-temperature ceramics withstanding temperatures 2000 K and above. During operation in air its surface is oxidized, giving rise to a crystalline oxide skeleton (HfO$_2$, ZrO$_2$) and a silica-rich borosilicate liquid that wets it, produced by the reactions:

\[
\text{ZrB}_2(c) + (5/2)O_2 \rightarrow \text{ZrO}_2(c) + \text{B}_2\text{O}_3(l, g)
\]

\[
\text{SiC}(c) + (3/2)O_2 \rightarrow \text{SiO}_2(l) + \text{CO}(g)
\]

respectively. Intense research is ongoing to characterize and enhance this scale as a barrier against oxygen (the scale microstructure can be seen in, for example, Fig. 4 of Opila et al., which apparently is superior to that of either monolithic diboride or SiC at the intended high temperatures (see Fig. 1). The reason for the first superiority (ZrB$_2$+SiC$>$ZrB$_2$) is well understood. Pure B$_2$O$_3$ melts at 450°C and evaporates rather quickly above 1100°C. In contrast, SiO$_2$ is a strong network former (pure SiO$_2$ has a glass transition temperature of 1175°C), with much larger viscosity as well as much smaller equilibrium vapor pressure than B$_2$O$_3$ (see Figs. 15 and 16 of Monteverde and Bellosio). Thus, oxygen diffusion should be more sluggish in the silica-rich liquid than in pure B$_2$O$_3$ ($l$), which furthermore will be evaporating rather quickly above 1100°C.

The reason for the second superiority (ZrB$_2$+SiC$>$SiC) is less well understood. The crystalline oxide phase ZrO$_2(c)$ formed is often highly porous—although in arc jet testing above 2000 K it appears that ZrO$_2(c)$ could sinter into a less porous compact layer, thereby potentially becoming protective also. Whether the in situ formed ZrO$_2(c)$, when fully dense, is as a significant barrier to oxygen diffusion as SiO$_2$ ($l$) in open-circuit condition, is an interesting question that depends on its electronic conductivity, which in turn depends on how the charge defects are compensated inside the crystal, related to the amount of impurities. Irrespective of the outcome of that discussion, however, if ZrO$_2(c)$ is quite porous its barrier function is lost, because gas-phase diffusion through the percolating cracks and pores, even in the Knudsen diffusion regime, is much easier than diffusion in condensed phases. In that case then, properties of the silica-rich liquid will control the effective barrier function of the scale, because it flows to fill in the cracks and pores of ZrO$_2(c)$, as well as forming an overlay on top (a “liquid roof,” see for instance Fig. 4 of Opila et al. and Fig. 6 of Rezaie et al.), thus occupying both parallel and serial oxygen transport routes.

We suggest an explanation for the second superiority (ZrB$_2$+SiC$>$SiC) in Section II, based on the notion that a protective condensed-phase oxide scale must be stable both thermochromically and mechanically, even when the volatility diagram predicts high vapor pressures ($>1$ atm = 101 325 Pa) in certain regions of the scale. We think the experiments suggest that with a porous ZrO$_2(c)$ skeleton, the high gas volatility problem can be avoided simply by the liquid phase retrograding somewhat afterwards, while still maintaining mechanical integrity by holding onto the outer ZrO$_2(c)$ skeleton with capillary forces. The porous ZrO$_2(c)$ skeleton acts as a condensing substrate and mechanical support to the borosilicate liquid. This is not available when oxidizing monolithic SiC, where the SiO$_2$ ($l$) is mechanically unstable against gas bubble coalescence and layer shear-off or spallation above the SiO boiling temperature.

In Section III, we make some molecular-level predictions regarding likely oxygen transport mechanisms in the borosilicate liquid, based on density functional theory (DFT) calculations. While it is commonly accepted that molecular O$_2$ permeate through the glassy network at low temperatures, the DFT calculation results suggest that network incorporated defects such as peroxyl linkage or oxygen-deficient centers will overtake molecular O$_2$ as dominant oxygen carriers at above $\sim 1500$ °C.
II. Thermochemical and Mechanical Stability Analysis of the Oxide Scale

ZrB2+SiC has a complex scale structure containing at least two condensed phases: ZrO2(c), which in this section is assumed to be a highly porous skeleton with percolating holes, and a silicarich liquid phase that wets the skeleton. Gas species of the greatest interest are B2O3, SiO, and CO, although BO, B2O2, B2O, etc. are also present and can be the dominant gas carriers in reducing conditions, and can play important roles in mass transport.\(^1\) SiO could evolve by for instance:

\[
2\text{SiO}_2(l) \rightarrow 2\text{SiO}(g) + \text{O}_2
\]

\(^{(3)}\)

(3) is a key reaction that has been used in constructing volatility diagrams.\(^{2,21,24,25}\) When in contact with SiO2(l), with decreasing oxygen chemical potential or the equivalent partial pressure (pO2), SiO will have higher equilibrium vapor pressure (pSiO\(^{+}\)). Volatility diagram of the ZrB2+SiC system\(^{\text{2,21}}\) indicates that when \(T > T_B \approx 1775^\circ\text{C}\), the peak equilibrium vapor pressure of SiO2 inside the scale could exceed 1 atm, which would then induce a boiling transition (gas bubbles can nucleate and grow inside the liquid). This violently disrupts the SiO2(l) scale in the case of oxidizing monolithic SiC. However, the scales of ZrB2+SiC and HfB2+SiC appear to be much more tolerant of such a boiling transition. It is precisely in this \(T > T_B\) regime that ZrB2+SiC and HfB2+SiC demonstrate oxidation resistance superior to monolithic SiC, which otherwise is considered a highly oxidation-resistant material (see Fig. 1).

We hereby suggest a “dynamic view” (Fig. 2(a)) and a “steady-state view” (Fig. 2(b)) of why ZrB2+SiC is superior to monolithic SiC. The two views are inherently consistent. Imagine a ZrB2+SiC specimen is gradually being heated up in an oxygen-rich environment like normal air (pO2 = 0.2 atm), initially from T \(\ll T_B\). At such high ambient pO2, a protective SiO2(l) film will condense on top from the very beginning,\(^{24}\) that wets the ZrO2(c) skeleton, leaving no voids at the base. At T\(\approx T_B\), monolithic SiC in fact resist oxidation better than ZrB2+SiC. Also at T\(\approx T_B\), the pSiO branch of the volatility diagram\(^{2,21}\) in contact with SiO2(l) has a formal thermodynamic definition but is not physically realizable as pure SiO gas bubbles, because any SiO gas bubble anywhere will be crushed by the high forces of surface tension and hydrostatic pressure, which we take to be 1 atm inside SiO2(l). However, as the temperature is brought up to T > T_B, a sharp transition happens inside SiO2(l). Now SiO gas bubbles can nucleate at the base, with \(\Delta p\approx p\text{SiO} = 1\ \text{atm} > 0\) working against the surface tension. The dynamic view (Fig. 2(a)) examines how the gas bubbles grow and coalesce, paying attention to the role of the ZrO2(c) skeleton.

It is likely that the ZrO2(c) skeleton will regulate gas bubble dynamics. Unlike unconstrained growth inside a completely liquid scale, gas bubbles (SiO, CO, B2O3, BO, O2, etc. mixture) in a semisolid porous scale are forced to grow into long fingers (a pressure difference of the order atm is large enough to displace a liquid, but usually not enough to displace a solid). Reaction (3) could then happen on one end of the gas finger, BO, B2O3, SiO, CO, etc. would then diffuse along the gas finger with O2 diffusing in the opposite direction, and finally when pO2 gets high enough, SiO could get reoxidized to form SiO2(l) on the other end of the finger,\(^{22}\) and B2O3, etc. would get solvated in the liquid and continue to diffuse up the scale. This is equivalent to a channeling transfer of SiO2(l) from one end of the finger to the other, which is mechanically untenable without the support and constraint of the ZrO2(c) skeleton. In reality the pores are tortuous instead of straight, giving the effusing SiO(g) much opportunity to react with O2(g) near the end, and the SiO2(l) product collected on the ZrO2(c) substrate. The skeleton may also impart significant mechanical integrity to the scale in the case of bubble outbreaks (bubble diameter constrained by the pore diameter) or under external shear flow, because SiO2(l) adheres strongly to a highly porous ZrO2(c) skeleton by capillary forces across a large contact area. In short, the dynamical view is that the ZrO2(c) skeleton helps to collect and retain the silica-rich liquid, playing an important mechanical role.

There is also a “steady-state” explanation (Fig. 2(b)), beginning with the interpretation of volatility diagrams.\(^{24,25}\) Volatility diagrams represent chemical equilibria when assuming some volatile gas species are in contact with certain condensed phases—solid or liquid. Solid or liquid makes a difference here, because a liquid could flow in or flow out, easily retreating from a region if necessary. If a certain condensed phase retreats, then an originally high volatile gas pressure—assuming the condensed phase was there—loses its significance. For instance, fig. 11 of Opekta et al.\(^2\) must appear more important than it really is in ZrB2+SiC oxidation, because we know there is no B2O3(l) to make contact with in reality at these temperatures. Another way of seeing this is that in reality all condensed-phase B2O3, if they exist, are solvated inside SiO2(l), with much lower activity than in pure B2O3(l), and thus the actual pB2O3 vapor pressure should be lowered in proportion and will not be as dangerously high as it originally looks. This understanding of the volatility diagram may be translated into the following rule: liquid phases will retreat from the region where some volatile gas species, were they in contact, will have high vapor pressure (approaching hydrostatic pressure inside the liquid), to region of lower vapor pressure according to the volatility diagram; after the retreat, the actual vapor pressure of the volatile gas species will
together, microstructural refinement of the oxide scale will lead to stronger capillary adhesion per unit volume, which could lead to significant improvement of the overall oxidation resistance.

The above rule comes from thermochemistry. Applying the rule to oxidizing monolithic SiC above $T_B$ (see Fig. 2(b) middle), we see that the only thermochromically sound steady-state arrangement is for $\text{SiO}_2(l)$ to retreat to the lower $p\text{SiO}_3$-$\text{high pO}_2$ region, and let gas-phase diffusion take over in the intervening gap, where there will be no condensed liquid phase, thus shutting down the high gas volatility. Unfortunately, although this setup is thermochromically and diffusion-kinetically sound, it is obviously mechanically unstable. The “scale” would easily shear off or spill. This is fundamentally because in monolithic SiC, with only a single condensed-phase oxide product, which is a liquid, there is no way to satisfy both thermochemical and mechanical stabilities simultaneously at $T>T_B$.

In contrast, when oxidizing $\text{ZrB}_2+\text{SiC}$, one gets two condensed-phase oxide products, $\text{ZrO}_2(c)$ itself has only low volatilities of $\text{ZrO}(g)$ and $\text{ZrO}_2(g)$ (see Fig. 11 of Opeka et al.).

Furthermore it is a solid. So it does not retreat from the high $\text{SiO}_2$ volatility region, maintaining mechanical connection with the main body. The silica-rich borosilicate liquid duly retreats from the high $\text{SiO}_2$ volatility region, thereby removing the high $\text{SiO}_2$ volatility automatically. This staggered placement of solid and liquid phases at $T>T_B$, with internal gas finger diffusion and gas-solid reactions (Fig. 2(b) bottom), is both thermochromically and mechanically sound if the $\text{ZrO}_2(c)$ skeleton is long enough, such that even after the retreat the liquid phase can still hold onto the solid by capillary forces, to have a “solid pillars, liquid roof” architecture as suggested by many experiments.

The actual oxidation of SiC particles at $T>T_B$ then no longer follows reaction (2), but directly

\[
\text{SiC}(c) + \text{O}_2(g) \rightarrow \text{SiO}_2(g) + \text{CO}(g)
\]  \hspace{1cm} (4)

a gas–solid reaction without going through the liquid phase, \(^{22}\) which will lead to a porous “SiC-depleted” substrate layer in the $\text{ZrB}_2+\text{SiC}$. \(^{11}\) The $\text{ZrO}_2(c)$ “solid pillars” will also grow longer at the base by gas–solid reaction, with $\text{O}_2(g)$ reactant and $\text{B}_2\text{O}_3(g)$ product. On the other end of the gas finger, we will have the reverse of reaction (3):

\[
2\text{SiO}_2(g) + \text{O}_2 \rightarrow 2\text{SiO}_2(l)
\]  \hspace{1cm} (5)

which replenishes the “liquid roof”.

The above explanation, if correct, could rationalize why the microstructure of $\text{ZrB}_2+\text{SiC}$ is important for its oxidation resistance, \(^{20}\) because the pore sizes of $\text{ZrO}_2(c)$ might be related to the preoxidation SiC particle sizes. As Gasch et al. mentioned, \(^{13}\) “at 20 volume percent SiC, if the SiC particles are assumed to be small spheres randomly distributed throughout the $\text{HfB}_2$ matrix, the amount of SiC should be above the percolation threshold. This means that the SiC particles form a network that is interconnected in three dimensions.” For a certain fixed volume fraction, smaller pores and better connectivity inside $\text{ZrO}_2(d)$ could enhance the collection and retention of the silica-rich liquid. Thus, nanoscale SiC particles might improve the oxidation resistance of $\text{ZrB}_2+\text{SiC}$, \(^{20}\) by refining the microstructure of the in situ formed $\text{ZrO}_2(c)$ skeleton.

The proposed view also explains why 70–80 vol% of the composite is dedicated to $\text{ZrB}_2$. It is seen that a porous $\text{ZrO}_2$ could be advantageous for the oxidation resistance for a mechanical reason (not a diffusion kinetics one), if there is also a liquid oxide product phase to “collaborate” with. The porous skeleton needs to be strong enough as well as sufficiently long, to have enough room for the liquid oxide phase to retreat outward. Otherwise, the two phases may still have to separate (“high volatility blows away the liquid roof”), and the entire system would lose oxidation protection. One cannot have too much SiC (and thus the liquid) and not enough oxide skeleton, and maintain the mechanical and thermochemical stabilities of the “solid pillars, liquid roof” architecture. Because capillary force holds the solid and liquid phases together, microstructural refinement of the oxide scale will lead to stronger capillary adhesion per unit volume, which could lead to significant improvement of the overall oxidation resistance.

### III. Oxygen Transport in Silica-Rich Liquid

From Section II model, we see that if ZrO2(c) has a percolating-holes microstructure, the borosilicate liquid will define the effective barrier against oxygen, irrespective of whether fully dense ZrO2 is intrinsically better barrier (in open-circuit condition) against oxygen or not than the borosilicate liquid, as the liquid occupies both serial and parallel oxygen transport pathways in the “solid pillars, liquid roof” architecture. In this section we focus on the atomic-level events that govern oxygen transport in the borosilicate liquid.

Experimentally, it is still challenging to accurately determine the composition profile of the borosilicate liquid because boron is a light element. According to the Hertz–Knudsen–Langmuir equation, \(^{32}\) the net evaporation flux of a species from a liquid surface is

\[
J = \alpha \Delta p / (2 \pi m k_B T)^{1/2}
\]  \hspace{1cm} (6)

Where $\Delta p$ is the difference between the equilibrium vapor pressure and the actual vapor pressure of the species at the surface, and $\alpha$ is a coefficient of order 1. Because pure B2O3 has much higher equilibrium vapor pressure than pure SiO2(l) in an oxygen-rich environment, a borosilicate liquid facing air would preferentially evaporate B2O3 instead of SiO2. Thus the borosilicate liquid should be overall silica rich, with a composition gradient that is B2O3 depleted at the liquid–air interface, and B2O3 enriched at the gas finger–liquid interface (Fig. 2(b)), as B2O3(g) and other boron-bearing gas species \(^{31}\) are carried along with SiO2(g) in the gas finger and get absorbed into the liquid. Previously, Bongiorno and Pasquarello have studied oxygen transport in pure silica glass \(^{28,33,34}\) using a multiscale modeling approach that combines high-level quantum mechanical (DFT) calculations of the diffusing oxygen species and local energy barriers, with kinetic Monte Carlo sampling of connected migration pathways. To bound the results, we decide to model a borosilicate liquid composition of equal B2O3 and SiO2 proportions.

One major challenge in modeling any glass or liquid is to have reliable atomic structures. We have adopted the structure generation approach of Van Ginthoven, Jonsson, and Corrales, \(^{35}\) which was shown to reproduce experimental pair distribution functions for pure silica. The approach requires a classical interatomic potential to perform long-time molecular dynamics (MD) simulations at the beginning, followed by further DFT optimizations. To generate the classical potential, we adopt the van Beest, Kramer, and van Santen parameterization \(^{36}\) for Si–O interactions, but fit B–O and Si–B interactions to a series of small DFT calculations for bulk B2O3, using the software package GULP. \(^{37}\) Then, starting from random positions for oxygen, boron and silicon atoms in the supercell, we perform a sequence of classical MD simulations at temperatures 6000, 5000, 4000, 3000, 2000, and 1000 K. The resulting structures were then used as input geometries for further DFT calculations (Vienna ab initio simulation program \(^{38,39}\) with spin-polarized PW91 functional, \(^{40}\) projector augmented wave method, \(^{41,42}\) plane-wave kinetic energy cutoff 400 eV). For our initial studies, a cubic supercell containing 14SiO2+7B2O3 formula units is used, with total 77 atoms. The average density is 2.3 g/cm$^3$. A typical liquid structure at $T=2500$ K, after further equilibration by ab initio MD, is shown in Fig. 3(a). It clearly has a framework structure with no long-range order, and contains with no dangling bonds (all Si are fourfold coordinated to O, and all B are threefold coordinated to O).

Based on these atomic structures, we have studied the thermodinamic stability and diffusion kinetics of solvated oxygen molecules O2 and atomic O+ in borosilicate liquid. The former stay inside the open cages of the framework and do not interact
such as Ar, as well as water) that the borosilicate liquid still maintains a very “rigid” framework at 2500°C. Indeed, pure silica is a strong glass-forming liquid, and its viscosity does not show a precipitous drop above the glass transition temperature. For instance, even at 2500°C, pure silica still has a shear viscosity \( \eta \approx 10^7 \) poise, which is a million times thicker than that of room-temperature water. This means the liquid still has a well-defined network structure at any given moment, and its topological change does not occur at the same timescale as, for instance, its own Si–O–Si bond stretching. Also, from the 11 ps \( ab \text{ initio} \) MD trajectory, we find the \( O_2^* \) is essentially trapped inside one cage. It just bounces back and forth many times inside a jiggling cage, with no possibility of escape within the MD simulation timescale. These facts suggest that one is still justified to use transition-state theory and numerical schemes like the NEB method\(^{34} \) to characterize diffusion of \( O_2^* \), despite it is embedded in a liquid. From our MD simulations, adding 50% \( B_2O_3 \) to silica does not seem to change this consideration qualitatively.

A complication for the NEB calculation is that unlike in crystals, diffusion inside an amorphous framework has a distribution of local minima and activation energies.\(^{33,34} \) Not all cages have the same volume, nor the same energy for opening up the constrictions (see movie S2) when \( O_2^* \) squeezes from one cage into the other. In Fig. 5 of Bongiorno et al.,\(^{33} \) we have shown a typical DFT–NEB-calculated MEP of \( O_2^* \) diffusion (vehicular diffusion mode). The forward hop barrier is 1.8 eV, whereas the backward hop barrier is 1.4 eV. These are somewhat higher than the 1.12 eV effective migration barrier that Bongiorno and Pasquarello\(^{34} \) predicted for \( O_2^* \) vehicular diffusion in pure silica, perhaps because of the \( B_2O_3 \) modifications to the network. More calculations are needed in order to have better statistics.

For vehicular diffusion inside a liquid, there is a well-known Stokes–Einstein relation:

\[
D(O_2^*) \sim k_b T / 6\pi \eta R(O_2^*)
\]

(7)

where \( R(O_2^*) \) is a nominal hydrodynamic radius of the molecule. Even though the Stokes–Einstein relation is quite successful in simple liquids, it can fail in network-forming liquids.\(^{46,47} \) Norton measured the permeation of gaseous oxygen through vitreous silica and found an activation energy of 27 kcal/mol (1.17 eV)\(^{48} \) for \( D(O_2^*) \), in substantial agreement with later measurements.\(^{49} \) However, the activation energy governing \( \eta \), the viscosity of vitreous silica, is in the range of 5.3–7.5 eV.\(^{49} \) So clearly Eq. (7) does not work. From our DFT modeling, the physics governing the activation energy of \( O_2^* \) vehicular diffusion is seen to be an \textit{elastic} deformation of the framework (elastic opening of the constrictions, see movie S2) without changing its network topology. But the physics behind the activation energy of \( \eta \) must involve network topology changes, which necessarily involve Si–O bond breaking.

In addition to \( O_2^* \) vehicular diffusion, oxygen transport may also occur by Grotthuss-type oxygen-hopping mechanisms,\(^{50} \) mediated by network defects such as peroxyl linkage\(^{27,28} \) or oxygen-deficient centers.\(^{29,30} \) These mechanisms would involve bond breaking, and typically higher effective activation energies—mostly due to the formation energies of such defects. Figure 3(b) shows one such pathway, where an \( O_2^* \) breaks up into two \( O^* \):

\[
O_2^* \rightarrow O^* + O^*
\]

(8)

The two \( O^* \) then move independently of each other for a while, and eventually recombine on the other side of the cage (see movie S3) in this particular NEB calculation setup. In node 3 of the calculated MEP (Fig. 3(b) inset), one \( O^* \) takes the form of a peroxyl linkage Si–O–O–B, while the other \( O^* \) takes the form of an additional B–O–B bridge, making the two boron atoms four-fold coordinated.

We find from multiple NEB calculations in the borosilicate framework that these coordination defects, once formed, can interconvert easily, suggesting low migration barriers, similar to

**Fig. 3.** (a) A typical borosilicate liquid structure (14SiO\(_2\)+7B\(_2\)O\(_3\), plus one solvated \( O_2^* \)) generated from a sequence of long-time classical molecular dynamics simulations, followed by density functional theory (DFT) molecular dynamics simulation at 2500°C. Note that the supercell has been replicated three times in all three dimensions to facilitate visualization of the framework. (b) A typical DFT calculated minimum energy path (MEP) of dissociation–migration–recombination reaction inside the borosilicate framework: \( O_2^* \rightarrow 2O^* \rightarrow O_2^* \), where oxygen exchange between \( O_2^* \) and the network occurs. The inset shows the atomic configuration (replotted for visualization) of node 3 on the MEP, which contains one peroxyl linkage (Si–O–O–B) and one extra B–O–B bridge. Oxygen: red, boron: orange, silicon: silver.
is the prevalent oxygen carrier concentration (per formula unit of SiO$_2$+B$_2$O$_3$), whereas the LHS has energy advantage. The classic enthalpy–entropy tradeoff in free energy then suggests that there exists a temperature $T_C$, below which O$_2^-$ is dominant in concentration, and above which O$^-$'s are dominant, if the borosilicate is in an oxygen-rich environment (the equivalent $p_{O_2}$ is high). In lower equivalent $p_{O_2}$ environment, oxygen-deficient centers 29,30 are also possible carriers.

In reference to O$_2$ in the gas phase, we find the average potential energy of O$_2^-$ solvated in borosilicate is 0.73 eV per molecule, which is essentially the elastic energy in the framework needed to accommodate the molecule. The average potential energy of O$^-$, on the other hand, is about 1.78 eV per O. These energies are used to compute the concentration of O$_2^-$ and O$^-$ in borosilicate in equilibrium with $p_{O_2} = 0.1$ atm, shown in Fig. 4. Note that $p_{O_2}$ scales linearly with $p_{O_2}$, whereas $c_0$ scales linearly with ($p_{O_2}$)$^{1/2}$. Thus, deeper and deeper into the scale, as the oxygen chemical potential gets lower and lower, the Grotthuss-type oxygen transport should become relatively more and more important.

Norton measured the solubility of O$_2^-$ in pure silica at 1078°C and $p_{O_2} = 1$ atm to be $1.9 \times 10^{-3}$ cm$^3$ STP O$_2$ gas per cm$^3$ silica. 8 This amounts to $5.1 \times 10^{16}$ per cm$^3$ silica or a dimensionless concentration of about $c = 10^{-5}$, at $p_{O_2} = 1$ atm. This is about two orders of magnitude higher than our DFT-predicted O$_2^-$ solubility in borosilicate, shown in Fig. 4. This could be due to the structural difference between pure silica framework and borosilicate framework. As Bongiorno and Pasquarello31 noted, the potential energy of O$_2^-$ depends sensitively on the cage interstice volume, and there is certainly a structural difference between pure silica and B$_2$O$_3$-modified networks. This could also be partly due to the intrinsic errors of PW91 density functional, 20 which are known to give large errors treating isolated molecules (the reference state), and nonbonding interactions (O$_2^-$ interactions with the framework).

The above uncertainties aside, it is still a rather conservative estimate that above $T_C \sim 1500\,^\circ$C the dominant oxygen carriers in the borosilicate “liquid roof” are network defects instead of molecular O$_2^-$, because there are other factors not shown in

![Fig. 4. Estimated concentrations of O$_2^-$ and O$^-$ (per formula unit of SiO$_2$+B$_2$O$_3$) inside borosilicate framework, in equilibrium with $p_{O_2} = 0.1$ atm.](image)

Fig. 4 that disfavors the Deal–Grove mechanism: (a) the DFT calculations indicate that the O$^-$’s not only have entropy advantage, but also mobility advantages over O$_2^-$, (b) intense aerothermal heating environment may introduce a significant level of dissociated oxygen on the outer liquid surface, 13,33 which would favor O$^-$ diffusion from a nonequilibrium kinetics perspective, (c) as $p_{O_2}$ drops from $\sim 10^9$ Pa on the outer liquid surface to $< 10^{-7}$ Pa equivalent at the internal gas finger–liquid interface (Fig. 2(b)) according to the volatility diagram, 22 the balance will shift more and more away from O$_2^-$ vehicular diffusion to network defect Grotthuss diffusion. Oxygen-deficient centers 29,30 may play a significant role in oxygen transport at low equivalent $p_{O_2}$. It seems plausible that oxygen in the borosilicate liquid could react with the underlying substrate or SiO(g), injecting oxygen vacancies (e.g., regions of high B and Si stoichiometry) into the liquid, which then diffuse up the scale to recombine with O$_2^-$ or O$^-$ somewhere inside the liquid. (d) In all the DFT calculations, we have only considered neutral network defects. Charging the defects may significantly greatly reduce their formation energies, 30,31 although we will then need to solve the complementary problem of what other defects compensate the charge and carry out ambipolar diffusion under open-circuit condition.

The mobility advantage of the peroxyl linkage over O$_2^-$ suggests that arc-jet testing 13,33 may introduce a nonequilibrium distribution of dissociated oxygen atoms on the surface, will likely lead to faster oxidation than ordinary furnace testing at the same temperature. Also, because the network defects are chemically incorporated into the network and thus interact more strongly with solutes than O$_2^-$, small changes in the glass chemistry could lead to large changes in the oxygen diffusivity by defect trapping/gettering, 26 much more than what Eq. (7) could have suggested.

IV. Summary

We present a congruent explanation of the oxidation protection of ZrB$_2$+SiC based on a “solid pillars, liquid roof” scale architecture, where the borosilicate liquid defines the effective diffusion barrier, and the solid zirconia collects and retains the liquid and provides mechanical support. Internal gas fingers will form as the liquid phase retreats to remove the high SiO volatility above a boiling transition temperature. At such high temperatures, to satisfy both thermochemical and mechanical stabilities, the “solid pillars, liquid roof” architecture seems to be a viable solution, not available to monolithic SiC.

Compared with the borosilicate liquid phase, whether fully dense zirconia is blocking or unblocking to oxygen in open-circuit condition depends on its electronic conductivity (transference number), which in turn depends on how the charge defects are compensated inside the crystal, related to the amount of impurities. If the zirconia phase has a highly porous microstructure, however, then the above discussion is likely irrelevant and the borosilicate liquid phase will control the effective diffusion barrier, because it will occupy both serial and parallel oxygen transport pathways.

At low temperatures, it is commonly accepted that molecular oxygen O$_2^-$ dominates oxygen transport. However, from first-principles calculations with detailed borosilicate atomic structures, it seems unlikely that this will remain the case at temperatures of practical interest for the ZrB$_2$+SiC thermal protection system (above 1500°C). This means that the oxidation rate will likely have a complex, sublinear dependence with respect to the external oxygen partial pressure. Also, if the oxygen carriers are chemically incorporated and interact strongly with the framework, there is hope that by tuning the glass composition, the carriers could be trapped, thereby slowing down oxygen diffusion.

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